Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	4376	((memory cell) near (region$1 area$1 part$1 portion$1)) with (peripher$2 near (region$1 area$1 part$1 portion$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 16:01
L2	3	1 and (remov$3 near2 (hard near mask) near2 (spacer$1 sidewall$1 (side near wall$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 15:54
L3	21	1 and (remov$3 with (hard near mask) with (spacer$1 sidewall$1 (side near wall$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 16:00
L4	0	((memory cell) near (region$1 area$1 part$1 portion$1)) AND (peripher$2 near (region$1 area$1 part$1 portion$1)) AND remov$3 AND (hard near mask) AND (spacer$1 sidewall$1 (side near wall$1)) AND (conduct$3 near spacer$1) AND (spac$3 near distance) AND (line near pattern$1) AND width AND (insulat$3 near (layer film)) AND (photoresist (photo near resist)) AND (depp near contact$1) AND (etch$1 near mask).CLM.	US-PGPUB; USPAT	OR	ON	2005/08/01 15:59
L5	642	(remov$3 with (hard near mask) with (spacer$1 sidewall$1 (side near wall$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 16:00
L6	429	5 and ((line near pattern$1) BL (bit neas line$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 16:01
L7	170	5 and ((line near pattern$1) BL (bit near line$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 16:02
L8	5021	((memory cell) near (region$1 area$1 part$1 portion$1)) same (peripher$2 near (region$1 area$1 part$1 portion$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/01 16:02

L9	14	8 and 7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/08/01 16:02